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SGS10N60RUFD

600 V, 10 A Short Circuit Rated IGBT

General Description

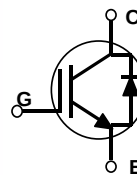
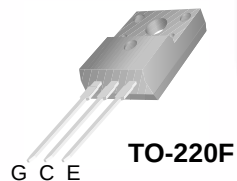
Fairchild's RUFD series of Insulated Gate Bipolar Transistors (IGBTs) provide low conduction and switching losses as well as short circuit ruggedness. The RUFD series is designed for applications such as motor control, uninterrupted power supplies (UPS) and general inverters where short circuit ruggedness is a required feature.

Features

- 10 A, 600 V, $T_C = 100^\circ\text{C}$
- Low Saturation Voltage: $V_{CE(sat)} = 2.2\text{ V @ } I_C = 10\text{ A}$
- Typical Fall Time.242ns at $T_J = 125^\circ\text{C}$
- High Speed Switching
- High Input Impedance
- Short Circuit Rating

Applications

Motor Control, UPS, General Inverter



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Description	SGS10N60RUFD	Unit
V_{CES}	Collector-Emitter Voltage	600	V
V_{GES}	Gate-Emitter Voltage	± 20	V
I_C	Collector Current @ $T_C = 25^\circ\text{C}$	16	A
	Collector Current @ $T_C = 100^\circ\text{C}$	10	A
$I_{CM(1)}$	Pulsed Collector Current	30	A
I_F	Diode Continuous Forward Current @ $T_C = 25^\circ\text{C}$	24	A
	Diode Continuous Forward Current @ $T_C = 100^\circ\text{C}$	12	A
I_{FM}	Diode Maximum Forward Current	92	A
T_{SC}	Short Circuit Withstand Time @ $T_C = 100^\circ\text{C}$	10	μs
P_D	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	55	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	22	W
T_J	Operating Junction Temperature	-55 to +150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_L	Maximum Lead Temp. for soldering purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

Notes :
(1) Repetitive rating : Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}(\text{IGBT})$	Thermal Resistance, Junction-to-Case	--	2.3	$^\circ\text{C/W}$
$R_{\theta JC}(\text{DIODE})$	Thermal Resistance, Junction-to-Case	--	3.7	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	--	62.5	$^\circ\text{C/W}$

Electrical Characteristics of IGBT $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV _{CES}	Collector-Emitter Breakdown Voltage	V _{GE} = 0 V, I _C = 250 uA	600	--	--	V
ΔB _V _{CES} /ΔT _J	Temperature Coeff. of Breakdown Voltage	V _{GE} = 0 V, I _C = 1 mA	--	0.6	--	V/°C
I _{CES}	Collector Cut-off Current	V _{CE} = V _{CES} , V _{GE} = 0 V	--	--	250	μA
I _{GES}	G-E Leakage Current	V _{GE} = V _{GES} , V _{CE} = 0 V	--	--	± 100	nA
On Characteristics						
V _{GE(th)}	G-E Threshold Voltage	I _C = 10 mA, V _{CE} = V _{GE}	5.0	6.0	8.5	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	I _C = 10 A, V _{GE} = 15 V	--	2.2	2.8	V
		I _C = 16 A, V _{GE} = 15 V	--	2.5	--	V
Dynamic Characteristics						
C _{ies}	Input Capacitance	V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz	--	660	--	pF
C _{oes}	Output Capacitance		--	115	--	pF
C _{res}	Reverse Transfer Capacitance		--	25	--	pF
Switching Characteristics						
t _{d(on)}	Turn-On Delay Time	V _{CC} = 300 V, I _C = 10 A, R _G = 20 Ω, V _{GE} = 15 V, Inductive Load, T _C = 25°C	--	15	--	ns
t _r	Rise Time		--	30	--	ns
t _{d(off)}	Turn-Off Delay Time		--	36	50	ns
t _f	Fall Time		--	158	200	ns
E _{on}	Turn-On Switching Loss		--	141	--	μJ
E _{off}	Turn-Off Switching Loss		--	215	--	μJ
E _{ts}	Total Switching Loss		--	356	500	μJ
t _{d(on)}	Turn-On Delay Time	V _{CC} = 300 V, I _C = 10 A, R _G = 20 Ω, V _{GE} = 15 V, Inductive Load, T _C = 125°C	--	16	--	ns
t _r	Rise Time		--	33	--	ns
t _{d(off)}	Turn-Off Delay Time		--	42	60	ns
t _f	Fall Time		--	242	350	ns
E _{on}	Turn-On Switching Loss		--	161	--	μJ
E _{off}	Turn-Off Switching Loss		--	452	--	μJ
E _{ts}	Total Switching Loss		--	613	860	μJ
T _{sc}	Short Circuit Withstand Time	V _{CC} = 300 V, V _{GE} = 15 V @ T _C = 100°C	10	--	--	μs
Q _g	Total Gate Charge	V _{CE} = 300 V, I _C = 10 A, V _{GE} = 15 V	--	30	45	nC
Q _{ge}	Gate-Emitter Charge		--	5	10	nC
Q _{gc}	Gate-Collector Charge		--	8	16	nC
Le	Internal Emitter Inductance	Measured 5mm from PKG	--	7.5	--	nH

Electrical Characteristics of DIODE $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
V _{FM}	Diode Forward Voltage	I _F = 12 A	T _C = 25°C	--	1.4	1.7	V
			T _C = 100°C	--	1.3	--	
t _{rr}	Diode Reverse Recovery Time	I _F = 12 A, di _F /dt = 200 A/μs	T _C = 25°C	--	42	60	ns
			T _C = 100°C	--	60	--	
I _{rr}	Diode Peak Reverse Recovery Current		T _C = 25°C	--	3.5	6.0	A
			T _C = 100°C	--	5.6	--	
Q _{rr}	Diode Reverse Recovery Charge		T _C = 25°C	--	80	180	nC
			T _C = 100°C	--	220	--	

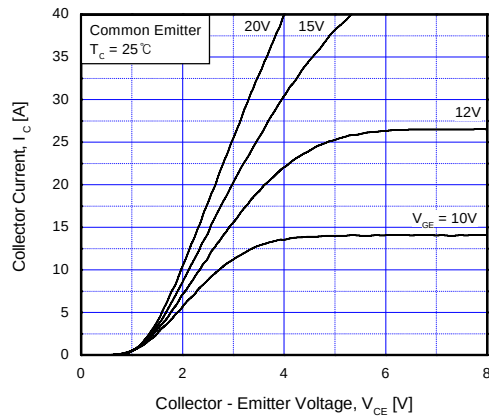


Fig 1. Typical Output Characteristics

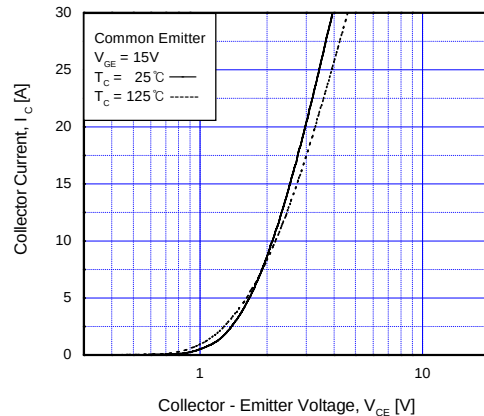


Fig 2. Typical Saturation Voltage Characteristics

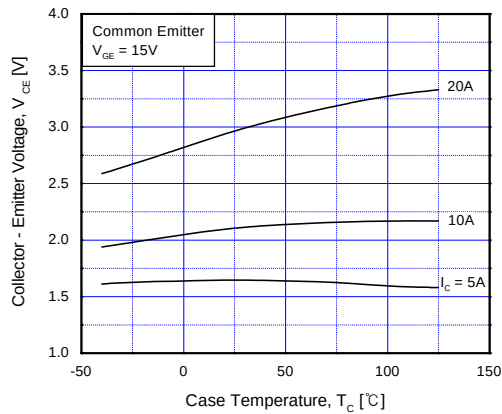


Fig 3. Saturation Voltage vs. Case Temperature at Variant Current Level

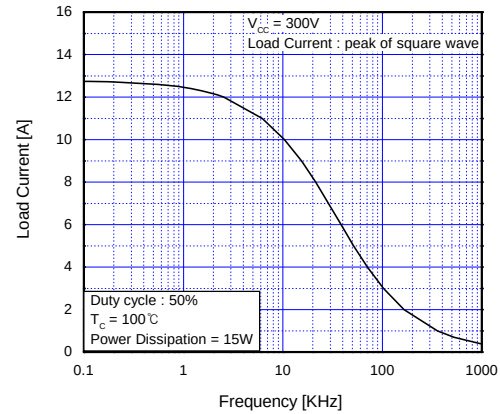


Fig 4. Load Current vs. Frequency

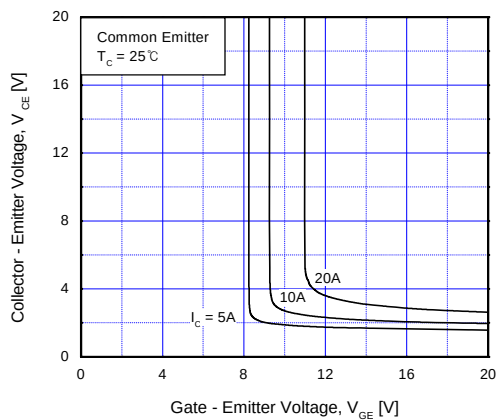


Fig 5. Saturation Voltage vs. V_{GE}

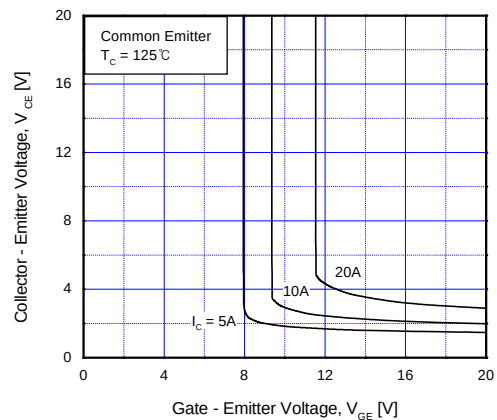


Fig 6. Saturation Voltage vs. V_{GE}

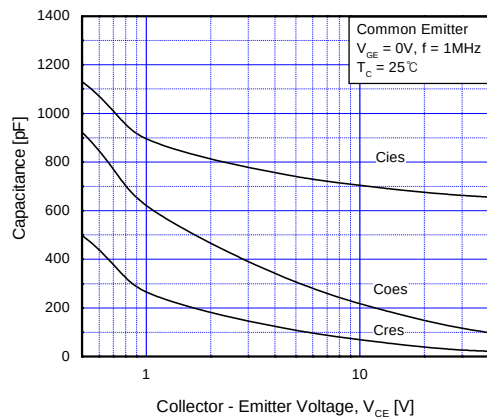


Fig 7. Capacitance Characteristics

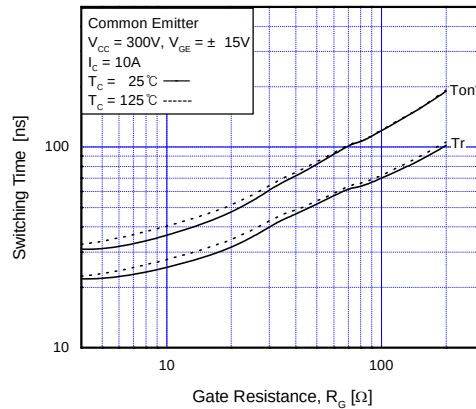


Fig 8. Turn-On Characteristics vs. Gate Resistance

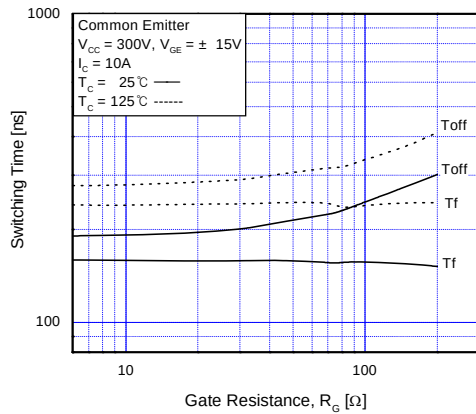


Fig 9. Turn-Off Characteristics vs. Gate Resistance

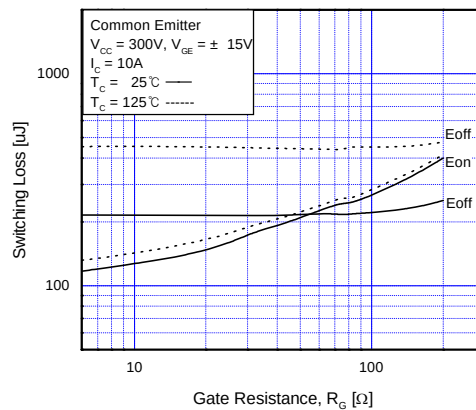


Fig 10. Switching Loss vs. Gate Resistance

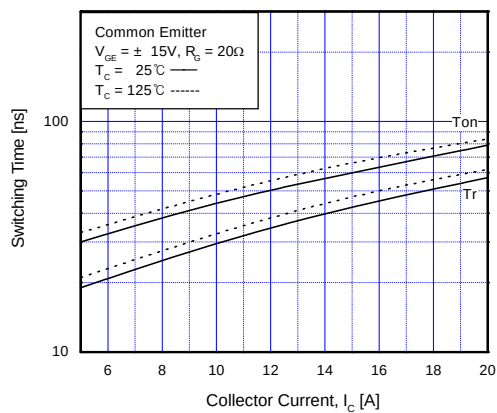


Fig 11. Turn-On Characteristics vs. Collector Current

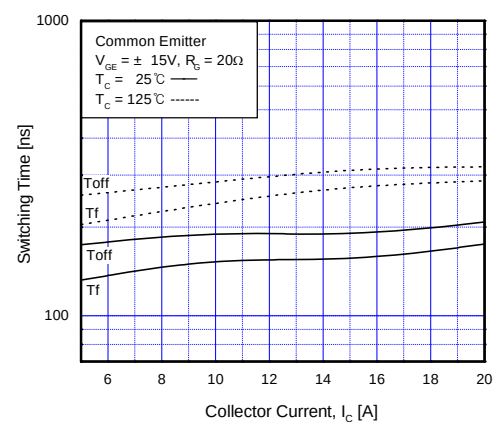


Fig 12. Turn-Off Characteristics vs. Collector Current

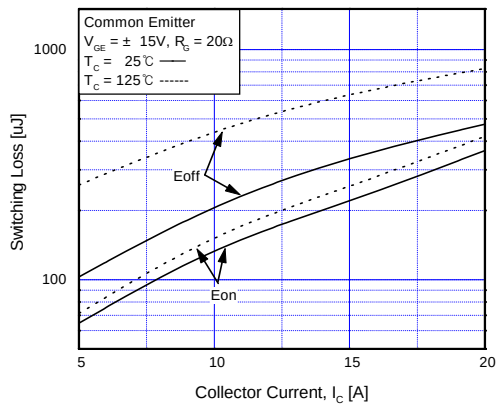


Fig 13. Switching Loss vs. Collector Current

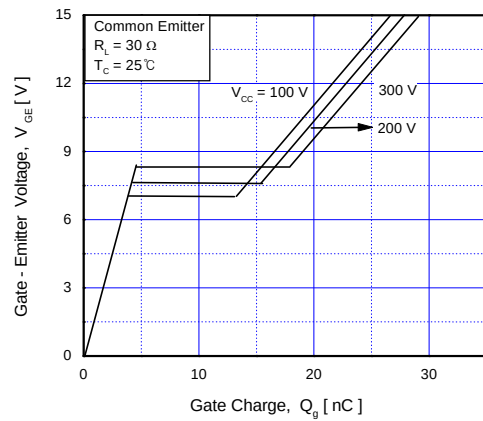


Fig 14. Gate Charge Characteristics

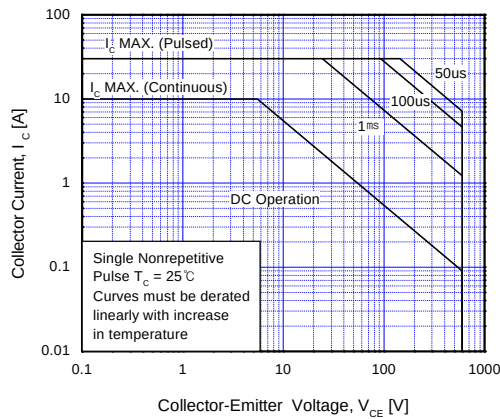


Fig 15. SOA Characteristics

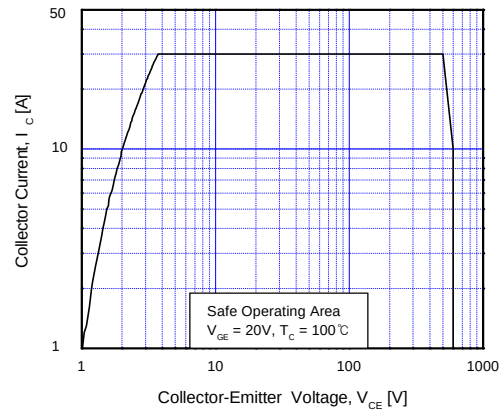


Fig 16. Turn-Off SOA Characteristics

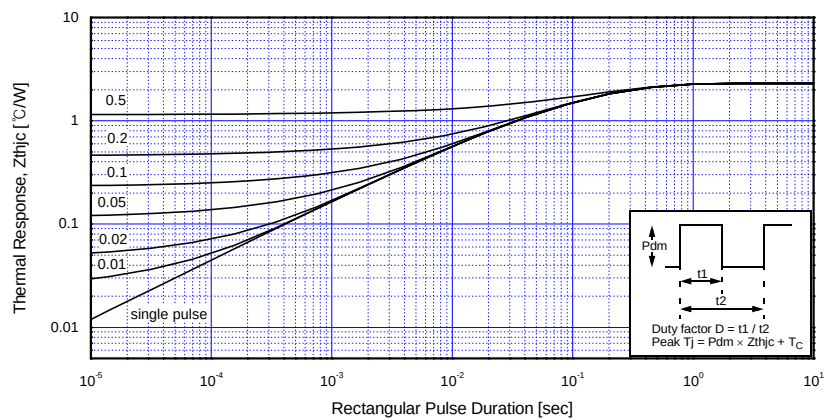


Fig 17. Transient Thermal Impedance of IGBT

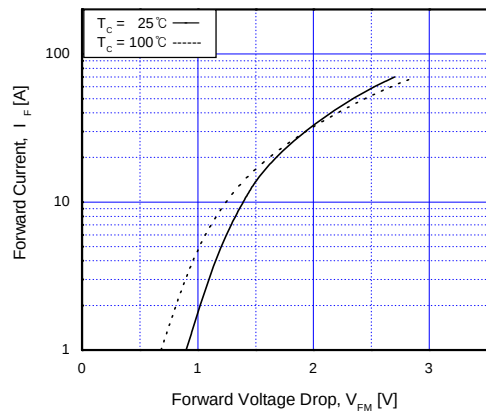


Fig 18. Forward Characteristics

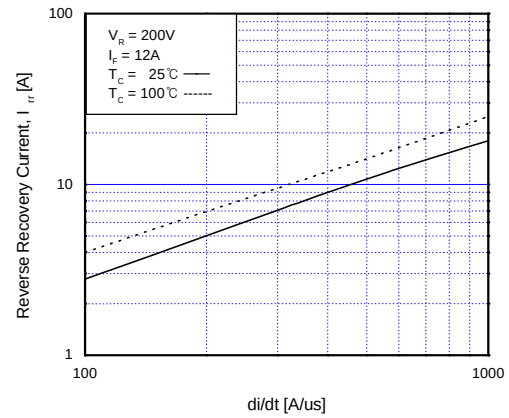


Fig 19. Reverse Recovery Current

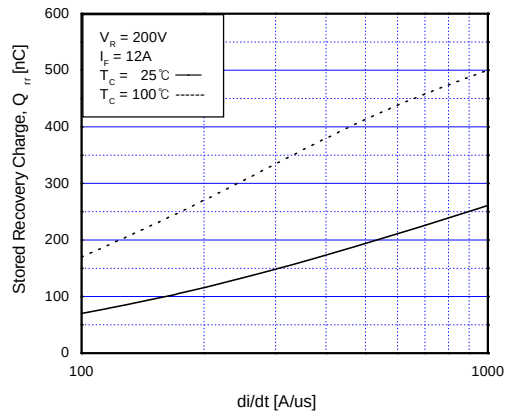


Fig 20. Stored Charge

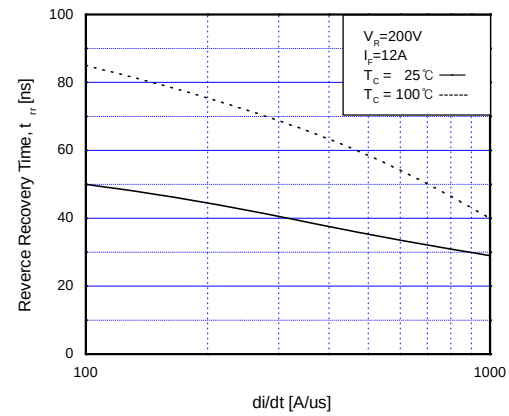


Fig 21. Reverse Recovery Time

Package Dimensions

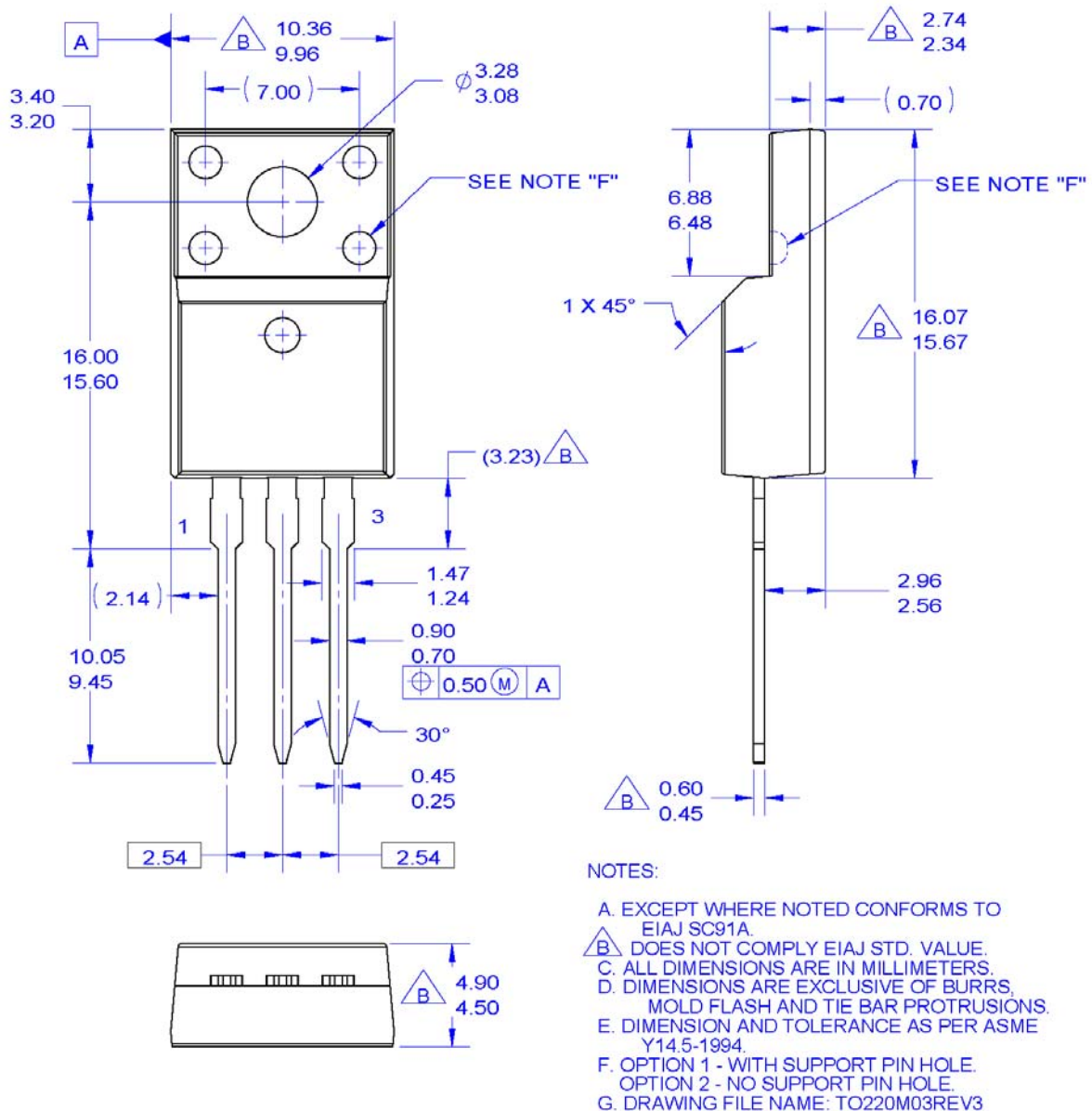


Figure 22. TO-220F 3L - TO220, MOLDED, 3LD, FULL PACK, EIAJ SC91, STRAIGHT LEAD

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